

Title (en)

GALVANIC GROWTH OF NANOWIRES ON A SUBSTRATE

Title (de)

GALVANISCHES WACHSEN VON NANODRÄHTEN AUF EINEM SUBSTRAT

Title (fr)

CROISSANCE GALVANIQUE DE NANOFILS SUR UN SUBSTRAT

Publication

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Application

**EP 22708886 A 20220222**

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Abstract (en)

[origin: WO2022184502A1] The invention relates to a device (1) for galvanically growing a plurality of nanowires (2) on a substrate (3), comprising a substrate holder (4) and a receptacle (5) for the substrate holder (4), wherein the device (1) is configured to allow the plurality of nanowires (2) to grow on the substrate (3) when the substrate holder (4) with the substrate (3) is received in the receptacle (5), the substrate holder (4) having an electronics unit (6) which is configured to influence the growth of the nanowires (2).

IPC 8 full level

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